



IN THE U.S. PATENT AND TRADEMARK OFFICE

For: SI-BASED RESONANT INTERBAND TUNNELING DIODES
AND METHOD OF MAKING INTERBAND TUNNELING DIODES

May 12, 2004

	CLAIMS REMAINING AFTER AMENDMENT		HIGHEST NUMBER PREVIOUSLY PAID FOR		PRESENT EXTRA	RATE	ADDITIONAL FEE
TOTAL	62	-	80	=	0	\$ 18	\$0.00
INDEPENDENT	6	-	6	=	0	\$ 86	\$0.00
<input type="checkbox"/> FIRST PRESENTATION OF A MULTIPLE DEPENDENT CLAIM						\$290	\$0.00
						TOTAL	\$0.00